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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Application Number	
Filing Date	June 29, 2001
First Named Inventor	Shumpei YAMAZAKI et al.
Group Art Unit	2823
Examiner Name	B. Kebede

740756-2330

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Examiner Initials	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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Examiner Signature	Brook Kebede	Date Considered	April 120, 2002

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